TOSHIBA PHOTOCOUPLER GaA{As LED & PHOTO-IC

TLP116

PDP(Plasma Display Panel) High Speed Interface FA(Factory Automation)

The Toshiba TLP116 consists of a GaAlAs light-emitting diode and an integrated high-gain, high-speed photodetector.

- Inverter logic (totempole output)
- Package type : MFSOP6
- Guaranteed performance over temperature : -40~100°C
- Power supply voltage : 4.5~5.5V
- Input thresholds current : I_{FHL}=5mA(Max.)
- Propagation delay time (tpHL/tpLH) : 60ns(Max.)
- Switching speed : 20MBd(TYP.)
- Common mode transient immunity : 10kV/us
- Isolation voltage : 3750Vrms
- UL Recognized : UL1577, File No.E67349

Truth Table

Input	LED	Tr1	Tr2	Output
Н	ON	OFF	ON	L
L	OFF	ON	OFF	Н



Weight: 0.09 g(Typ.)

Pin Configuration (Top View)





0.1uF bypass capacitor must be connected between pins 6 and 4

Absolute Maximum Ratings (Ta=25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	١ _F	20	mA
Q	Forward current derating (Ta≥85°C)	ΔIF/ΔTa	-0.5	mA/°C
ш	Peak transient forward current (Note1)	I _{FPT}	1	А
	Reverse voltage	VR	5	V
Я	Output current	IO	10	mA
CTO	Output voltage	VO	6	V
ETE(Supply voltage	V _{CC}	6	V
B	Output power dissipation	PO	40	mW
Oper	ating temperature range	Topr	-40~100	°C
Stora	ge temperature range	Tstg	-55~125	°C
Lead	solder temperature(10s)	Tsol	260	°C
Isolat (A	ion voltage .C,1min.,R.H.≤60%,Ta=25°C) (Note2)	BVs	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Recommended Operating Conditions

Characteristic		Symbol	Min	Тур.	Max	Unit
Input current, ON		I _{F(ON)}	8	_	18	mA
Input voltage , OFF		V _{F(OFF)}	0	_	0.8	V
Supply voltage	(Note3)	V _{CC}	4.5	5.0	5.5	V
Operating temperature		Topr	-40		100	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Correlation between Input current, switching speed and drive circuit (reference information).

Input current (IF)	test Circuit	Typical switching speed
12mA	1 (Page 4)	21 – 23 MBd
8mA	1 (Page 4)	18 – 20 MBd
8mA	2 (Page 4,With Speed up capacitor)	23 – 27 MBd

Note1 : Pulse width PW≤1us,300pps.

Note2: This device is regarded as a two terminal device : pins 1 and 3 are shorted together, as are pins 4,5 and 6.

Note3 : The detector of this product requires a power supply voltage (VCC) of 4.5 V or higher for stable operation. If the VCC is lower than this value, an ICC may increase, or an output may be unstable. Be sure to use the product after checking the supply current, and the operation of a power-on/-off.

Electrical Characteristics

(Unless otherwise specified, Ta=-40 to 100°C,VCC=4.5~5.5V)

Characteristic	Symbol	Test Circuit	Conditions	Min.	Тур.	Max.	Unit
Input forward voltage	VF	_	I _F =10mA ,Ta=25°C	_	1.3	1.5	V
Temperature coefficient of forward voltage	ΔV _F /ΔTa		I _F =10mA		-2.0		mV/°C
Input reverse current	IR	—	V _R =5V,Ta=25°C	_	—	10	μA
Input capacitance	CT	_	V=0,f=1MHz,Ta=25°C	_	70		pF
Logic low output voltage	V _{OL}	1	I _{OL} =1.6mA, I _F =12mA,V _{CC} =5V	_		0.4	V
Logic high output voltage	VOH	2	I _{OH} =-0.02mA, V _F =1.05V,V _{CC} =5V	4.0			V
Logic low supply current	ICCL	3	I _F =12mA	_		5.0	mA
Logic high supply current	^I ССН	4	V _F =0V	_	_	5.0	mA
Input current logic low output	IFHL	_	I _O =1.6mA,V _O <0.4V	_		5	mA
Input voltage logic high output	V _{FLH}		I _O =-0.02mA,V _O >4.0V	0.8			V

*All typical values are at Ta=25°C, V_{CC}=5V, I_F(ON)=12mA unless otherwise specified

Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Capacitance input to output	CS	V = 0,f = 1MHz (Note 2)	_	0.8	_	pF
Isolation resistance	R _S	R.H. ≤ 60%,V _S = 500V (Note 2)	1×10 ¹²	10 ¹⁴	_	Ω
		AC,1 minute	3750	_	_	V _{rms}
Isolation voltage	BVS	AC,1 second,in oil	-	10000	_	Vde
		DC,1 minute,in oil	—	10000		Vuc

Note 4:A ceramic capacitor(0.1 µF) should be connected from pin 6 to pin 4 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypass may impair the switching property. The total lead length between capacitor and coupler should not exceed 1 cm.

Switching Characteristics

(Unless otherwise specified, Ta=-40 to 100°C,V_{CC}=4.5~5.5V)

Characteristic	Symbol	Test Circuit	Con	ditions	Min.	Тур.	Max.	Unit
Propagation delay time to logic high output	tpHL	_	I _F =0→12mA	R _{IN} =100 Ω C _L =15pF (Note 5)	_	_	60	ns
Propagation delay time to logic low output	tpLH	5	I _F =12→0mA		_		60	ns
Propagation delay time to logic high output	tpHL		V _{IN} =0→5V (I _F =0→8mA)	R _{IN} =470 Ω C _{IN=} 27pF C _L =15pF (Note 5)	_		60	ns
Propagation delay time to logic low output	tpLH	6	V _{IN} =5→0V (I _F =8→0mA)		_		60	ns
Switching time dispersion between ON and OFF	tpHL- tpLH		I _F =12mA , R _{IN} =100 Ω , CL=15pF (Note 5)		_		30	ns
Output fall time(90-10%)	tf	5	I _F =0→12mA	R _{IN} =100Ω	_	15	_	ns
Output rise time(10-90%)	tr		I _F =12→0mA	(Note 5)		15	_	ns
Common mode transient immunity at high Level output	СМ _Н	7	V _{CM} =1000Vp-p Vo(Min)=4V,Ta=	o,IF=0mA, ⊧25°C	10000	_	_	V/us
Common mode transient immunity at low level output	CML	1	V _{CM} =1000Vp-p Vo(Max)=0.4V, ⁻	o,I _F =12mA, ſa=25°C	-10000			V/us

*All typical values are at Ta=25°C

Note 5 : CL is approximately 15pF which includes probe and Jig/stray wiring capacitance.

TEST CIRCUIT 1 : VOL



TEST CIRCUIT 3 : ICCL



TEST CIRCUIT 2 : VOH



TEST CIRCUIT 4: ICCH



TEST CIRCUIT 5 : tpHL , tpLH



TEST CIRCUIT 6 : tpHL , tpLH



TEST CIRCUIT 7 : Common-Mode Transient Immunity Test Circuit





*: The above graphs show typical characteristics.



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